

Researchers advance graphene spintronics with 1D contacts to improve mobility in nanoscale devices

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Credit: University of Manchester

Researchers at The University of Manchester may have cleared a significant hurdle on the path to quantum computing, demonstrating stepchange improvements in the spin transport characteristics of nanoscale graphene-based electronic devices.



The team—comprising researchers from the National Graphene Institute (NGI) led by Dr. Ivan Vera Marun, alongside collaborators from Japan and including students internationally funded by Ecuador and Mexico—used monolayer graphene encapsulated by another 2D material (hexagonal boron nitride) in a so-called van der Waals heterostructure with one-dimensional contacts (main picture, above). This architecture was observed to deliver an extremely high-quality graphene channel, reducing the interference or electronic 'doping' by traditional 2D tunnel contacts.

'Spintronic' devices, as they are known, may offer higher energy efficiency and lower dissipation compared to conventional electronics, which rely on charge currents. In principle, phones and tablets operating with spin-based transistors and memories could be greatly improved in speed and <u>storage capacity</u>, exceeding Moore's Law.

As published in *Nano Letters*, the Manchester <u>team</u> measured <u>electron</u> <u>mobility</u> up to 130,000cm²/Vs at low temperatures (20K or -253°C). For purposes of comparison, the only previously published efforts to fabricate a device with 1D contacts achieved mobility below 30,000cm²/Vs, and the 130k figure measured at the NGI is higher than recorded for any other previous graphene channel where spin transport was demonstrated.

The researchers also recorded spin diffusion lengths approaching 20µm. Where longer is better, most typical conducting materials (metals and semiconductors) have spin diffusion lengths

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